

NPN 3.0A 60V Middle Power Transistor

Parameter	Value
V_{CEO}	60
I _C	3A

Features

1) Suitable for Middle Power Driver

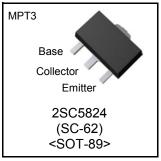
2) Complementary PNP Types: 2SA2071

3) Low $V_{CE(sat)}$

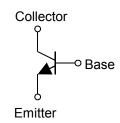
 $V_{CE(sat)}$ =0.50V(Max.) (I_C/I_B =2A/200mA)

4) Lead Free/RoHS Compliant.

Outline



•Inner circuit



Applications

Motor driver , LED driver Power supply

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SC5824	MPT3	4540	T100	180	12	1,000	UP

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	60	V
Collector-emitter voltage		V_{CEO}	60	V
Emitter-base voltage	V _{EBO} 6		6	V
Collector current	DC	I _C	3.0	А
	Pulsed	I _{CP} ^{*1}	6.0	А
Power dissipation		P_{D}^{*2}	0.5	W
		P_{D}^{*3}	2.0	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	−55 to +150	°C

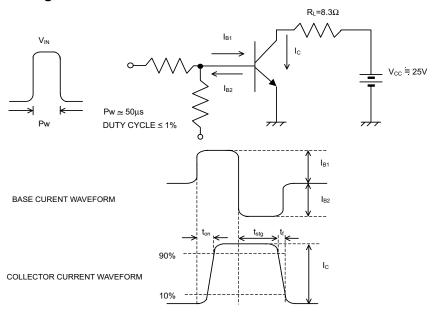
- *1 Pw=100ms, single pulse
- *2 Each terminal mounted on a reference land
- *3 Mounted on a ceramic board (40×40×0.7 mm)

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	60	-	-	V
Collector-base breakdown voltage	BV _{CBO}	I _C = 100μA	60	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = 100μA	6	ı	-	V
Collector cut-off current	I _{CBO}	V _{CB} = 40V	-	-	1	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 4V	-	-	1	μА
Collector-emitter saturation voltage	V _{CE(sat)} *1	I _C = 2A, I _B = 200mA	-	200	500	V
DC current gain	h _{FE}	$V_{CE} = 2V, I_{C} = 100mA$	120	-	390	-
Transition frequency	f _T *1	$V_{CE} = 10V, I_{E} = -100 \text{mA}$ f=10MH _Z	-	200	-	MHz
Output capacitance	C _{ob}	$V_{CB} = 10V$, $I_E = 0A$ f = 1MHz	-	20	-	pF
Turn-on time	t _{on} *2	I _C =3A	-	50	-	ns
Storage time	t _{stg} *2	I_{B1} =300mA I_{B2} = -300mA	-	150	-	ns
Fall time	t _f *2	V _{cc} ≃25V	-	30	-	ns

^{*1} Pulsed

•Switching time test circuit



^{*2} See switching time test circuit

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

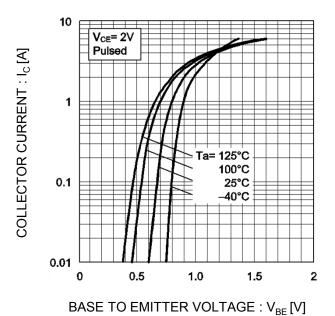
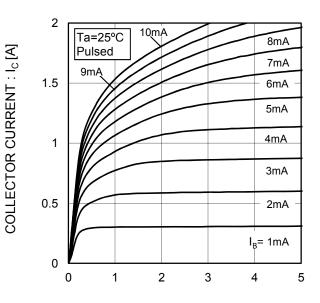


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V_{CE} [V]

Fig.3 DC Current Gain vs. Collector Current(I)

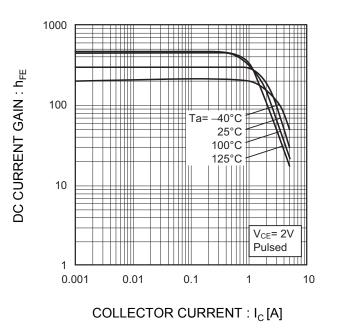
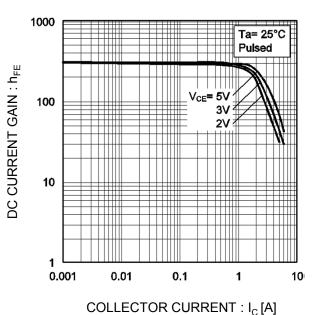


Fig.4 DC current Gain vs. Collector Current (II)



●Electrical characteristic curves(Ta = 25°C)

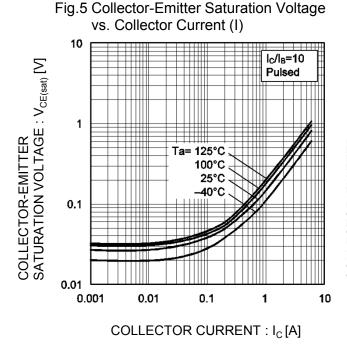
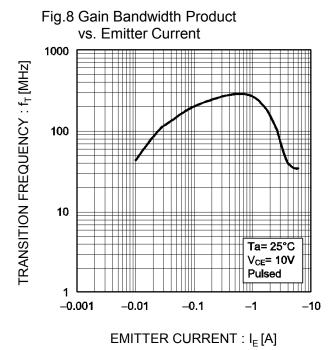


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II) 10 Ta= 25°C COLLECTOR-EMITTER SATURATION VOLTAGE : V_{CE(sat)} [V] Pulsed 1 $I_{\rm C}/I_{\rm B}=20/1$ 0.1 10/1 0.01 0.001 0.01 0.1 10 COLLECTOR CURRENT : I_C[A]

Fig.7 Base-Emitter Saturation Voltage vs. Collector Current 10 I_C/I_B=10/1 BASE-EMITTER SATURATION VOLTAGE : V_{BE(sat)} [V] Pulsed Ta= -40°C 25°C 100°C 125°C 1 0.1 0.001 0.01 0.1 1 10 COLLECTOR CURRENT: Ic [A]



●Electrical characteristic curves(Ta = 25°C)

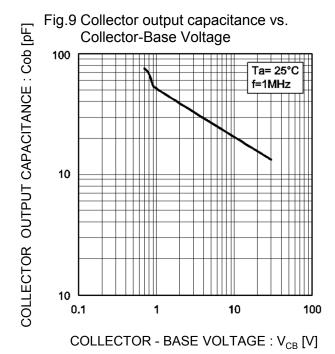
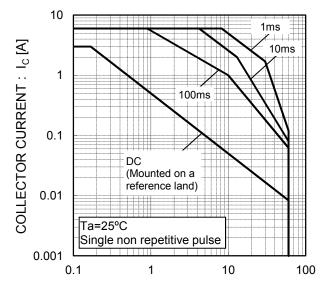


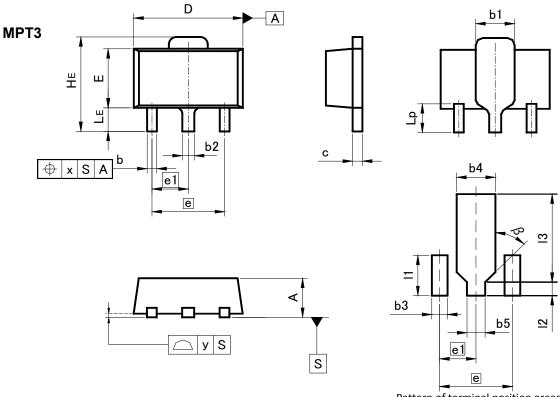
Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : $V_{CE}\left[V\right]$

Data Sheet 2SC5824

●Dimensions (Unit : mm)



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
С	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
Е	2.40	2.70	0.094	0.106	
е	3.0	00	0.1	18	
e1	1.	50	0.0	59	
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
Х	-	0.15	_	0.006	
У	_	0.10	-	0.004	

DIM	MILIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
b3	_	0.65	-	0.026	
b4	_	1.70	-	0.067	
b5	-	0.75	-	0.030	
l1	_	1.71	-	0.067	
12	-	0.58	-	0.023	
13	_	3.72	_	0.146	
β	45°		45	0	

Dimension in mm / inches

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